

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		40	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	50	Α	
	Pulsed Drain Current	T _C = 25°C	See Figure 4		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	24	mJ	
P _D	Power Dissipation		75	W	
	Derate Above 25°C		0.5	W/ ^o C	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	52	°C/W	

Notes:

1: Current is limited by bondwire configuration.

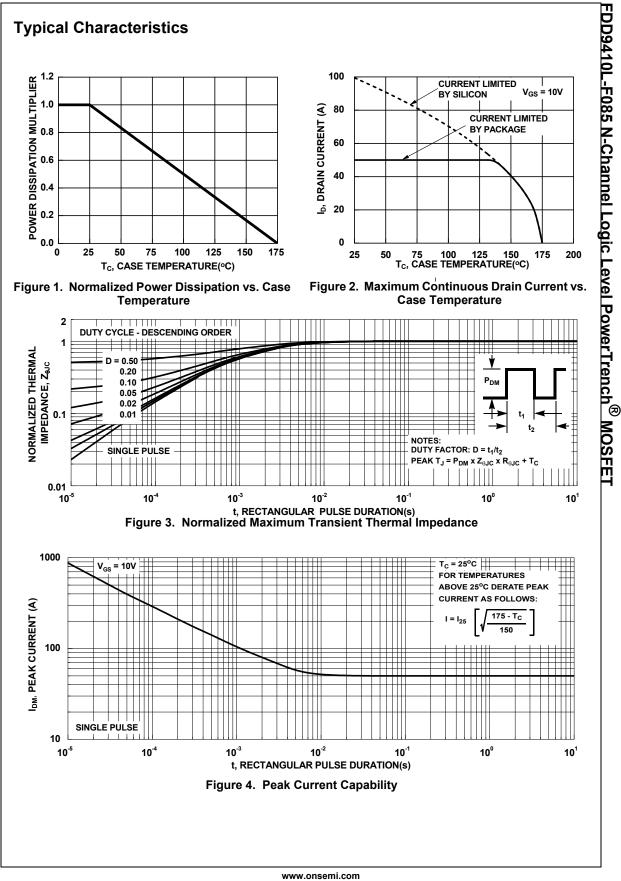
2: Starting $T_J = 25^{\circ}$ C, L = 30 μ H, $I_{AS} = 40$ A, $V_{DD} = 40$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche.

3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

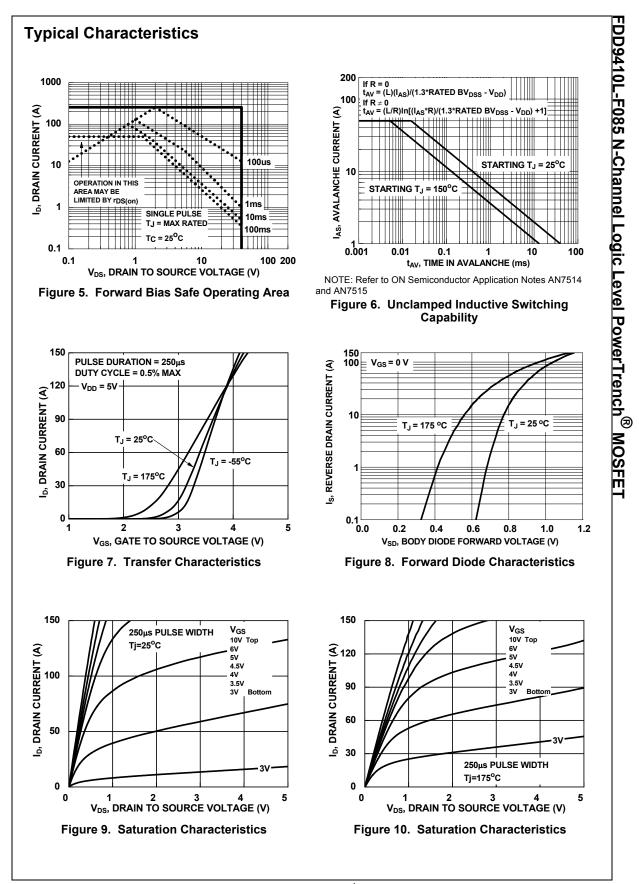
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD9410L	FDD9410L-F085	D-PAK(TO-252)	13"	16mm	2500units

	Parameter	Test Conditions		Тур.	Max.	Unit
Off Cha	aracteristics					
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	40	-	-	V
I _{DSS}	Drain-to-Source Leakage Current	V_{DS} =40V, T_{J} = 25°C V_{GS} = 0V T_{J} = 175°C (Note 4	-	-	1	μA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = 0V$ $I_J = 175^{\circ}C$ (Note 2 V _{GS} = ±20V	·) - -	-	1 ±100	mA nA
	racteristics	.63			2.00	
	_		10	1 0	2.0	V
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$ $I_D = 50A, V_{GS} = 4.5V$	1.0	1.8 5.0	3.0 6.5	v mΩ
R _{DS(on)}	Drain to Source On Resistance	$I_D = 50A, V_{GS} = 4.5V$ $I_D = 50A, T_J = 25^{\circ}C$		3.3	4.2	mΩ
		$V_{GS} = 10V$ $T_{J} = 175^{\circ}C$ (Note		6.0	7.6	mΩ
Junam	ic Characteristics					
-						
C _{iss}	Input Capacitance	V _{DS} = 20V, V _{GS} = 0V,	-	1960	-	pF
C _{oss}	Output Capacitance	= 1 f = 1 MHz	-	615	-	pF
C _{rss}	Reverse Transfer Capacitance		-	41	-	pF
R _g	Gate Resistance	f = 1MHz	-	1.9	-	Ω
Q _{g(ToT)}	Total Gate Charge	V_{GS} = 0 to 10V V_{DD} = 32V	-	29	43	nC
ጋ _{g(th)}	Threshold Gate Charge	$V_{GS} = 0$ to 2V $I_D = 50A$	-	4	-	nC
ପୁ _{gs}	Gate-to-Source Gate Charge		-	6	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge		-	5	-	nC
Switchi	ng Characteristics					
t _{on}	Turn-On Time		-	-	22	ns
t _{d(on)}	Turn-On Delay		-	8	-	ns
t _r	Rise Time	V _{DD} = 20V, I _D = 50A,	-	7	-	ns
d(off)	Turn-Off Delay	V_{GS} = 10V, R_{GEN} = 6 Ω	-	25	-	ns
	Fall Time		-	5	-	ns
t _f	Turn-Off Time		-	-	45	ns

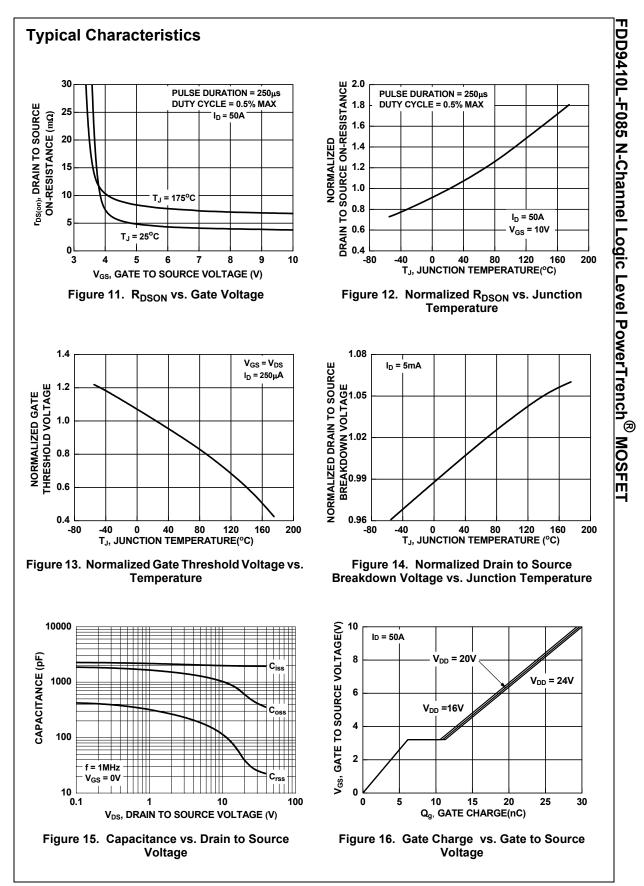


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